IN THE SPECIFICATION

DRAFT

Please amend the paragraphs at page 1, lines 8-11 as follows:

Related subject matter is also disclosed in commonly assigned patent application entitled,
"Anti-Fuse Memory Cell With <u>Asymmetric Assymetric Breakdown Voltage," serial number</u>

09/918,307, filed July 30, 2001 having atterney docket number 10519/52 and filed on even date herewith.